

v06.0920

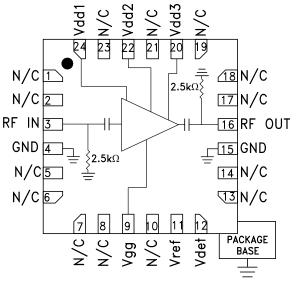
## GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

#### **Typical Applications**

The HMC1082LP4E is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT & SATCOM
- Marine Radar
- Military EW & ECM

#### **Functional Diagram**



#### Features

High Saturated Output Power: 26 dBm @ 26% PAE High Output IP3: 35 dBm High Gain: 22 dB High P1dB Output Power: 24 dBm DC Supply: +5V @ 220 mA Compact 24 Lead 4x4 mm SMT Package: 16 mm<sup>2</sup>

#### **General Description**

The HMC1082LP4E is a GaAs pHEMT MMIC driver amplifier with an integrated temperature compensated on-chip power detector which operates between 5.5 and 18 GHz. The amplifier provides 22 dB of gain, +35 dBm Output IP3, and +24 dBm of output power at 1 dB gain compression, while requiring 220 mA from a +5V supply. The HMC1082LP4E is capable of supplying +26 dBm of saturated output power with 26 % PAE and is housed in a compact leadless 4x4 mm plastic surface mount package.

The HMC1082LP4E is an ideal driver amplifier for a wide range of applications including point-to-point radio from 5.5 to 18 GHz and marine radar at 9 GHz. The HMC1082LP4E may also be used for 6 to 18 GHz EW and ECM applications.

#### **Electrical Specifications** $T_A = +25^{\circ}$ C, Vdd1 = Vdd2 = Vdd3 = +5V, Idd = +220 mA <sup>[1]</sup>

Parameter	Min	Тур.	Max	Min	Тур.	Max	Min	Тур	Max	Units
Frequency Range		5.5 - 6.5			6.5 - 17			17 - 18		GHz
Gain	21.5	23.5		20.5	22.5		20	22		dB
Gain Variation over temperature		0.0121			0.0101			0.015		dB/°C
Input Return Loss		22			12			7.5		dBm
Output Return Loss		10			14			17.5		dBm
Output Power for 1 dB Compression (P1dB)	21	24		21	24		20.5	23.5		dBm
Saturated Output Power (Psat)		25.5			26			24.5		dBm
Output Third Order Intercept (IP3) [2]		36			35			33.5		dBm
Supply Current (Idd)		220			220			220		mA

[1] Adjust Vgg between -2 to 0V to achieve Idd = 220mA typical

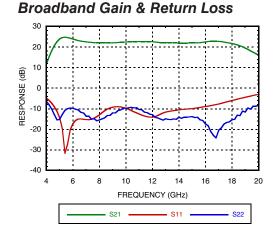
[2] Measurement taken at Pout / tone = +12dBm

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

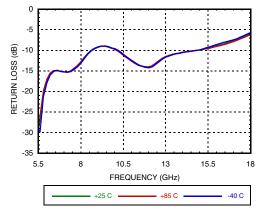
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



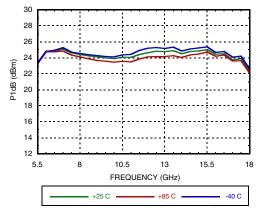
## GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

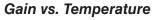


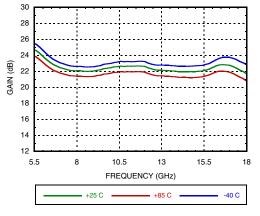
Input Return Loss vs. Temperature



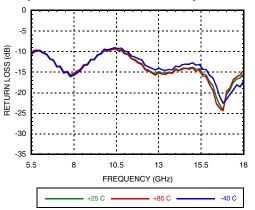
#### P1dB vs. Temperature



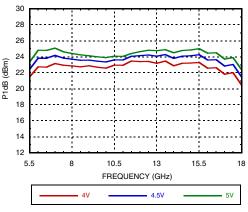




**Output Return Loss vs. Temperature** 









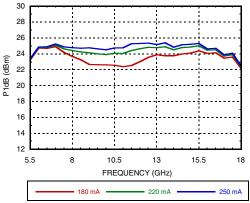
Psat vs. Temperature

v06.0920

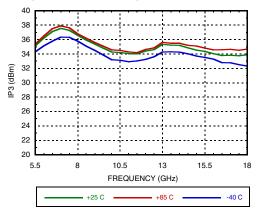
### GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

#### 30 28 26 24 Psat (dBm) 22 20 18 16 14 12 5.5 8 10.5 13 15.5 18 FREQUENCY (GHz) +25 C +85 C -40 C

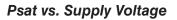
#### P1dB vs. Supply Current

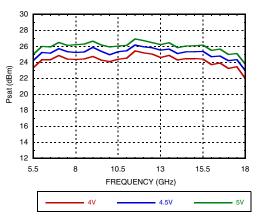


#### Output IP3 vs. Temperature [1]

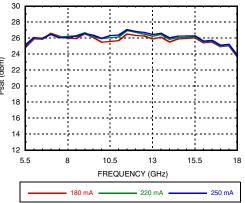


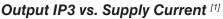
[1] Pout/Tone = +12 dBm

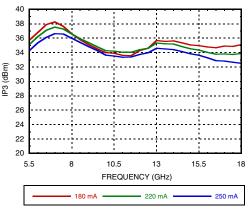




#### Psat vs. Supply Current







 28
 26

 24
 22

 20
 13

 13
 15.5

 18
 18

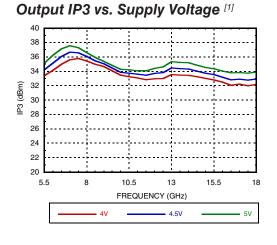
 CY (GHz)
 5.5

 = 220 mA
 250 mA

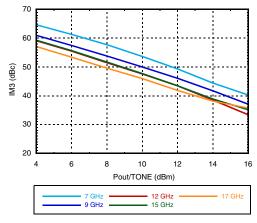
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



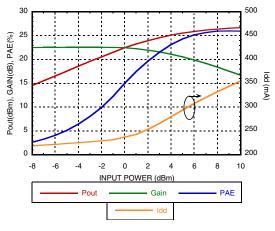
## GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz



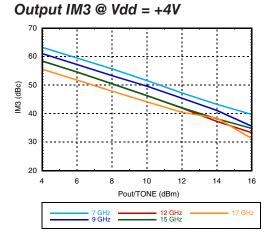
Output IM3 @ Vdd = +4.5V

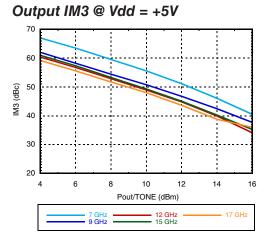


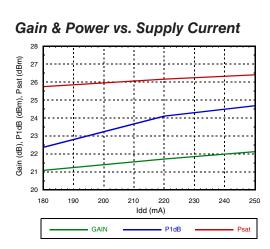
#### Power Compression @ 12 GHz



[1] Pout/Tone = +12 dBm



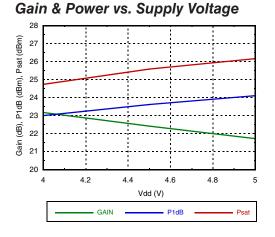




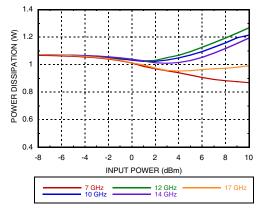


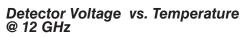
v06.0920

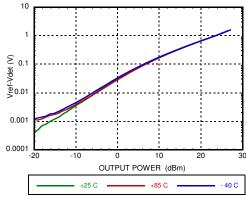
## GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

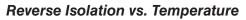


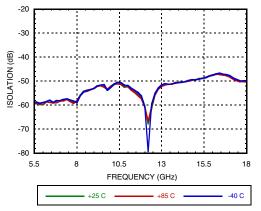
#### **Power Dissipation**

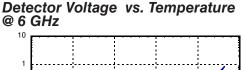


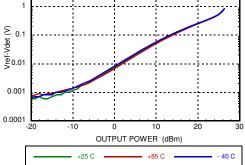


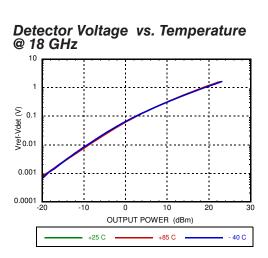










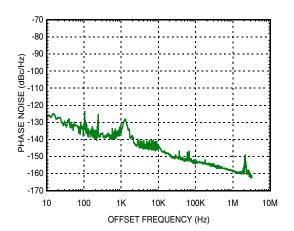


For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

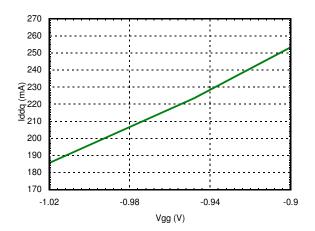


## GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

Additive Phase Noise Vs Offset Frequency, RF Frequency = 8 GHz, RF Input Power = 3 dBm (P1dB)



#### Iddq Vs Vgg



Notes:



v06.0920

### GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	5.5V		
RF Input Power (RFIN)	20 dBm		
Channel Temperature	175 °C		
Continuous Pdiss (T=85 °C) (derate 20mW/°C	1.81W		
Thermal Resistance (R <sub>TH</sub> ) (junction to ground paddle)	49.8 °C/W		
Operating Temperature	-40°C to +85°C		
Storage Temperature	-65°C to 150°C		
ESD Sensitivity (HBM)	Class 1A, Passed 250V		

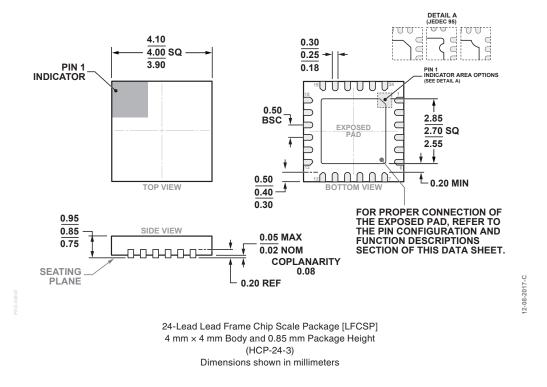
#### Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)
+4	220
+4.5	220
+5	220

Adjust Vgg1 to achieve Idd = 220mA



#### **Outline Drawing**



#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating <sup>[2]</sup>	Package Marking <sup>[1]</sup>	
HMC1082LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	<u>H1082</u> XXXX	

[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



## GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

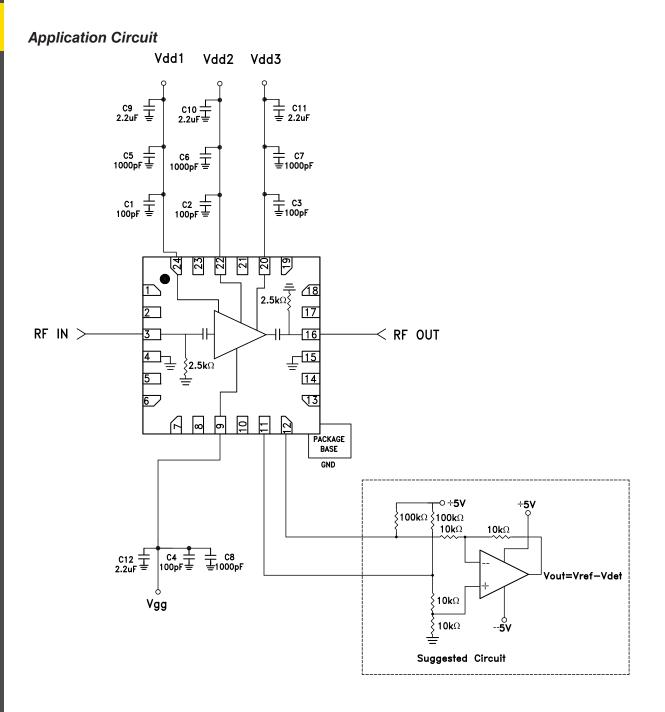
#### **Pin Descriptions**

Pin Number	Function	Description	Pin Schematic
1, 2, 5, 6, 7, 8, 10, 13, 14, 17, 18, 19, 21, 23	N/C	These pins are not connected internally, however all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RF IN	This pin is DC coupled and matched to 50 Ohms.	$\begin{array}{c c} RFIN & \bigcirc & & & \\ & & & \\ & & & \\ & & & \\ & & = \end{array} \end{array} $
4, 15	GND	These pins and package bottom must be connected to RF/DC ground.	
9	Vgg	Gate control for amplifier. External bypass capacitors of 1000pF, 100pF and 2.2uF are required.	Vggo
11	Vref	DC bias of diode biased through external resistor used for temperature compensation of Vdet. See application circuit.	−−−○Vref
12	Vdet	DC voltage representing RF output power rectified by diode which is biased through an external resistor. See application circuit.	OVdet
16	RF OUT	This pin is DC coupled and matched to 50 Ohms.	RFOUT $\bigcirc$
24, 22, 20	Vdd1, Vdd2, Vdd3	Drain bias voltage for amplifier. External bypass capac- itors of 1000pF, 100pF and 2.2uF are required.	Vdd1,2,3



v06.0920

### GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz



9



**Evaluation PCB** 

## HMC1082LP4E

### GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

littit€ **(B**) (16)  $(\mathbf{D})$ VDD2 VDD3 VDD1 C6 🕇 Π C2: C3 C1 **U1** J2 J1 C12 Ţ C82 22 Ć 100 ÍDÌ Ð  $(\mathbf{IS})$ 600-00819-00-1 THRU CAL J4 J3 N N ÍDŻ

### List of Materials for Evaluation PCB EV1HMC1082LP4 [1]

Item	Description		
J1, J2	PCB Mount SMA RF Connector		
J5 - J12	DC Pin		
J9	VDD4 on Evaluation Board is +5V		
C1 - C4	100pF Capacitor, 0402 Pkg.		
C5 - C8	1000pF Capacitor, 0402 Pkg		
C9 - C12	2.2uF Capacitor, 0402 Pkg.		
R1, R2	40.2k Ohm Resistor, 0402 Pkg.		
U1	HMC1082LP4E		
PCB [2]	600-00819-00 Evaluation Board		
[1] Reference this number when ordering Complete Evaluation PCB			

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Analog Devices upon request. AMPLIFIERS - LINEAR & POWER - SMT

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D